

HMC1049LP5E

Data Sheet

RF Amplifier 0.3-20GHz lo NOISE amp

Manufacturers Analog Devices, Inc

Package/Case QFN-32

Product Type RF Amplifiers

RoHS Pb-free Halide free

Lifecycle



Images are for reference only

Please submit RFQ for HMC1049LP5E or **Email to us: sales@ovaga.com** We will contact you in 12 hours.

RFO

General Description

The HMC1049LP5E is a GaAs MMIC low noise amplifier(LNA) that operates between 0.3 GHz and 20 GHz. This LNAprovides 15 dB of small signal gain, 1.8 dB noise figure, and anIP3 output of 29 dBm, yet requires only 70 mA from a 7 Vsupply. The P1dB output power of 14.5 dBm enables the LNA tofunction as a local oscillator (LO) driver for balanced, I/Q, orimage rejection mixers. VDD can also be applied to Pin 21, although Pin 21 requires a bias tee with>

Features

Low noise figure: 1.8 dB

P1dB output power: 14.5 dBm

PSAT output power: 17.5 dBm

High gain: 15 dB

Output IP3: 29 dBm

Supply voltage:>

 50Ω matched input/output (I/O)

32-lead, 5 mm × 5 mm LFCSP package: 25 mm²

HMC1049SCPZ-EP Supports Defense and Aerospace Applications (AQEC standard)

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Controlled manufacturing baseline

1 assembly/test site

Application

Test instrumentation

High linearity microwave radios

VSAT and SATCOM

Military and space



Related Products



HMC3653LP3BE
Analog Devices, Inc
QFN-12



HMC253AQS24

Analog Devices, Inc 24-SSOP (0.154, 3.90mm Width)



HMC358MS8GE

Analog Devices, Inc MSOP-8



HMC453ST89E

Analog Devices, Inc ST89E



HMC441LP3E

Analog Devices, Inc QFN-16



HMC948LP3E

Analog Devices, Inc LP3



HMC490

Analog Devices, Inc SMD



HMC618ALP3E

Analog Devices, Inc QFN-16